- 23. (New) The method of claim 19, further comprising providing an oscillating control signal to the pass circuit.
- 24. (New) The method of claim 23, further comprising using a ring oscillator to provide the oscillating control signal to the pass circuit.
- 25. (New) The method of claim 19, further comprising using a pass control circuit to apply a desired voltage to the internal node, thereby forcing the voltage at the internal node to the desired voltage.
- 26. (New) The method of claim 19, wherein the pass circuit comprises:

a pass gate having first, second, and third terminals, the first terminal coupled to a pass control circuit, the second terminal coupled to the internal node, the third terminal coupled to the pin; and

a capacitor coupled between the first terminal of the pass gate and the pass control circuit such that a voltage at the first terminal of the pass gate is driven to cause a voltage at the second terminal voltage to be passed to the third terminal for reading the voltage at the internal node.

- 27. (New) The method of claim 26, wherein the pass gate comprises an n-channel MOS transistor.
- 28. (New) A method for forcing a voltage at an internal node of an integrated circuit to a desired level, the method comprising:

coupling a pass circuit between the internal node and a pin of the integrated circuit; applying a voltage of the desired level to the pin;

using a reset circuit to activate the pass circuit; and

driving the pass circuit to pass the applied voltage from the pin to the internal node, thereby forcing the voltage at the internal node to the desired level.



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29. (New) The method of claim 28, further comprising using a pass control circuit to drive the pass circuit.

- (New) The method of claim 28, wherein the pass control circuit comprises an n-channel 30. MOS transistor having a drain coupled to the internal node, the n-channel MOS transistor configured to, when turned on, pass the voltage at the internal node to a source of the n-channel MOS transistor and to the pass circuit.
- (New) The method of claim 28, further comprising providing an oscillating control 31. signal to the pass circuit.
- (New) The method of claim 31, further comprising using a ring oscillator to provide the 32. oscillating control signal to the pass circuit.
- (New) The method of claim 28, wherein the pass circuit comprises: 33.

a pass gate having first, second, and third terminals, the first terminal coupled to a pass control circuit, the second terminal coupled to the internal node, the third terminal coupled to the pin; and

a capacitor coupled between the first terminal of the pass gate and the pass control circuit such that a voltage at the first terminal of the pass gate is driven to cause a voltage at the second terminal voltage to be passed to the third terminal for reading the voltage at the internal node.



SUPPLEMENTAL PRELIMINARY AMENDMENT

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CIRCUIT AND METHOD FOR MEASURING AND FORCING AN INTERNAL VOLTAGE OF AN INTEGRATED CIRCUIT Title:



(New) The method of claim 33, wherein the pass gate comprises an n-channel MOS 34. transistor.

The Examiner is invited to contact the below-signed attorney to discuss any questions which may remain with respect to the present application.

Respectfully submitted,

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CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail, in an envelope addressed to: Commissioner of Patents, Washington, D.C. 20231, on day of December, 2000.

Name

Signature